A low-cost and green-solvent-processable hole-transport

material enabled by a traditional bidentate ligand for highly

efficient inverted perovskite solar cells

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Experimental Section

Scheme S1 Overall synthetic route of M0 and M1



M0. ¹H NMR (400 MHz, Chloroform-*d*) δ 8.69 (d, J = 8.7 Hz, 2H), 8.03 (d, J = 1.8 Hz, 2H), 7.87 (dd, J = 8.6, 1.9 Hz, 2H), 7.77 (s, 2H), 7.60 (d, J = 8.7 Hz, 4H), 7.12 (d, J = 8.8 Hz, 4H), 7.05 (d, J = 8.6 Hz, 8H), 6.86 (d, J = 9.0 Hz, 8H), 3.82 (s, 12H; CH₃). ¹³C NMR (101 MHz, Chloroform-*d*) δ 155.94, 140.89, 138.70, 132.36, 128.85, 127.72, 127.46, 126.68, 125.62, 125.47, 123.15, 120.85, 114.76, 55.54. HRMS: C₅₂H₄₄N₂O₄ calcd: 784.3296, found: 783.3294.

M1. ¹H NMR (400 MHz, Chloroform-*d*) δ 9.40 (d, J = 2.3 Hz, 2H), 8.31 (d, J = 2.3 Hz, 2H), 7.83 (s, 2H), 7.61 (d, J = 8.7 Hz, 4H), 7.13 (d, J = 8.9 Hz, 8H), 7.07 (d, J = 8.7 Hz, 4H), 6.88 (d, J = 9.0 Hz, 8H), 3.82 (s, 12H; CH₃). ¹³C NMR (101 MHz, Chloroform-*d*) δ 156.01, 148.96, 140.28, 135.00, 131.82, 128.66, 128.20, 127.73, 126.75, 126.71, 120.24, 114.62, 55.32. HRMS: C₅₂H₄₂N₄O₄ calcd: 786.3206, found: 786.3203.





Positive mode









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	Commercially	Price	Dosage	Cost/CNY
	available chemicals			
Step 1	4-bromoaniline	500 g/130 CNY	1.36 g	0.34
	<i>p</i> -iodoanisole	500 g/826 CNY	4.59 g	7.48
	CuI	25 g/35 CNY	44.2 mg	0.05
	1,10-phenanthroline	100 g/210 CNY	42.5 mg	0.09
	КОН	500 g/18 CNY	3.4 g	0.12
	toluene	500 mL/30 CNY	68 mL	4.08
	petroleum ether	500 mL/12 CNY	850 mL	20.40
	CH ₂ Cl ₂	500 mL/12 CNY	850 mL	20.40
	silica gel	500 g/15 CNY	340 g	10.20
Step 2	bis(pinacolato)diboron	500 g/900 CNY	1.87 g	3.37
	Pd(dppf)Cl ₂	10 g/800 CNY	170 mg	13.60
	KOAc	500 g/40 CNY	1479 mg	0.12
	dioxane	1000 mL/200 CNY	42.5 mL	8.50
	petroleum ether	500 mL/12 CNY	850 mL	20.40
	CH ₂ Cl ₂	500 mL/12 CNY	850 mL	20.40
	silica gel	500 g/15 CNY	340 g	10.20
Step 3	3,8-Dibromo-1,10-	25 g/4128 CNY	0.6 g	99.1
	phenanthroline			
	Pd(PPh ₃) ₄	10 g/530 CNY	212.5 mg	11.22
	K ₂ CO ₃	500 g/20 CNY	765 mg	0.03
	THF	500 mL/20 CNY	57 mL	2.27
	petroleum ether	500 mL/12 CNY	700 mL	17.04
	CH ₂ Cl ₂	500 mL/12 CNY	70 mL	17.04
	silica gel	500 g/15 CNY	283 g	8.52
total cost				295
				(45 US\$)

 Table S1
 Detailed calculation of cost for the synthesis of 1 g of M1

Table S2. Solubility test of M0 and M1 in chlorobenzene or ethyl acetate at room temperature

UTM	Chlorobenzene	Ethyl acetate	
птм	(mg mL ⁻¹)	(mg mL ⁻¹)	
M0	~45	~5	
M1	~22	~0.9	



Fig. S7 Transmittance spectroscopy for the pure ITO (black line), M0 on ITO, and M1 on ITO.



Fig. S8 TGA curves of M0 and M1 which was measured at a heat ramp of 10 $^{\circ}\mathrm{C}$ min^{-1}

Hole and electron mobilities were characterized using the space-charge-limited current (SCLC) method. The device structure of ITO/PEDOT:PSS/HTM/Au was used for hole-only devices. The SCLC mobilities were calculated using the MOTT-Gurney equation:

$$J = 9/8 \epsilon_0 \epsilon_r \mu V^2/d^3$$

where *J* is the current density, ε_r is the relative dielectric constant of the active layer, herein, we use a relative dielectric constant of 3 for the polymer. ε_0 is the permittivity of empty space, μ is the mobility of hole or electron, and *d* is the thickness of the active layer, *V* is the internal voltage in the device, and $V = V_{appl} - V_{bi}$, where V_{appl} is the voltage applied to the device, and V_{bi} is the built-in voltage resulting from the relative work function difference between the two electrodes (in the hole-only and the electron-only devices, the V_{bi} values can be neglected).



Fig. S9 The corresponding $J^{1/2}$ -*V* curves for the hole-only devices are based on the pure HTM films with a device structure of ITO/PEDOT:PSS/HTM/Au.



Fig. S10 XRD patterns of the perovskite films on M0 and M1

HTM/perovskite	Crystal size (110)	
	(nm)	
M0/perovskite	33.03	
M1/perovskite	46.58	

 Table S3. The calculated crystal size from XRD data.



Fig. S11 Topographic AFM images of the HTM films for (a) M0 and (b) M1 spun from ethyl acetate solution



Fig. S12 (a)–(d) Statistics of photovoltaic parameters for the inverted PVSCs with M0 and M1 HTMs processed by CB. A total of 20 cells for each type of devices were used for statistics



Fig. S13 (a)–(d) Statistics of photovoltaic parameters for the inverted PVSCs with M0 and M1 HTMs processed by EA. A total of 20 devices were used for statistics.